
	<p><b>SI4386DY-T1-GE3</b></p>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI4386DY-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 11A 8-SOIC</p> <p><b>Datenblätter:</b>  <a href="#">SI4386DY-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 798200 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	<a href="#">SI4386DY-T1-GE3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET N-CH 30V 11A 8-SOIC
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	798200 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	1.47W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11A (Ta)
Rds On (Max) @ Id, Vgs	7 mOhm @ 16A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI4386DY-T1-GE3 ist neu im Original, Suche SI4386DY-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4386DY-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4386DY-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI4384DY-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 10A 8-SOIC</p>	 <p><b>SI4386DY-T1-E3</b> Vishay / Siliconix MOSFET N-CH 30V 11A 8-SOIC</p>	 <p><b>SI4386DY-T1-E3..</b> VISHAY SI4386DY-T1-E3.. VISHAY</p>	 <p><b>SI4388DY-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 10.7A 8-SOIC</p>
 <p><b>SI4386DY-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 11A 8-SOIC</p>	 <p><b>SI4386DY</b> VISHAY SI4386DY VISHAY</p>	 <p><b>SI4388DY-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 10.7A 8-SOIC</p>	 <p><b>SI4388DY-T1-E3</b> Vishay / Siliconix MOSFET 2N-CH 30V 10.7A 8-SOIC</p>

heiße Teile

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|--|---|---|---|--|
|  SI4362DY         |  SI4362DY-T1     |  SI4362DY-T1-E3  |  SI4362DY-T1-E3.  |  SI4364DY         |
|  SI4364DY-T1      |  SI4364DY-T1-E3  |  SI4366DY-T1-E3  |  SI4368DY         |  SI4368DY-T1-E3   |
|  SI4368DY-T1-E3   |  SI4370DY-T1-E3  |  SI4376DY-T1-E3  |  SI4378DY-T1      |  SI4378DY-T1-E3   |
|  SI4378DY-T1-E3   |  SI4382DY-T1-E3  |  SI4384DY        |  SI4384DY-T1-E3   |  SI4384DY-T1-E3   |
|  SI4384DY-T1-E3.. |  SI4386DY        |  SI4386DY-T1-E3  |  SI4386DY-T1-E3   |  SI4386DY-T1-GE3  |
|  SI4388DY         |  SI4388DY-T1-GE3 |  SI4388DY-T1-GE3 |  SI4390DY         |  SI4390DY-T1      |
|  SI4390DY-T1-E3   |  SI4390DY-T1-E3  |  SI4390DY-T1-E3  |  SI4392ADY        |  SI4392ADY-T1-E3  |
|  SI4392DY         |  SI4392DY-T1-E3  |  SI4392DY-T1-E3. |  SI4392DY-T1-E3.. |  SI4394DY         |
|  SI4394DY-T1-E3   |  SI4396DY        |  SI4396DY-T1-E3  |  SI4396DY-T1-E3   |  SI4398DY-T1-E3   |
|  SI4398DY-T1-E3   |  SI4401BDY-T1-E3 |  SI4401BDY-T1-E3 |  SI4401BDY-T1-E3. |  SI4401BDY-T1-GE3 |

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